INTEGRATED CIRCUITS

DATA SHEET

SA58641

High performance mixer FM IF system with high-speed RSSI

Objective data 2004 Dec 16





High performance mixer FM IF system with high-speed RSSI

SA58641

DESCRIPTION

The SA58641 is a high performance monolithic FM IF system with high-speed RSSI incorporating a mixer/oscillator, two limiting intermediate frequency amplifiers, quadrature detector, logarithmic received signal strength indicator (RSSI), voltage regulator, wideband data output and fast RSSI op amps. The SA58641 is available in 20-lead SSOP (shrink small outline package).

The SA58641 was designed for high bandwidth portable communication applications and will function down to 2.7 V. The RF section is similar to the famous SA605. The data output has a minimum bandwidth of 600 kHz. This is designed to demodulate wideband data. The RSSI output is amplified. The RSSI output has access to the feedback pin. This enables the designer to adjust the level of the outputs or add filtering.

SA58641 incorporates a power-down mode which powers down the device when Pin 8 is LOW. Power down logic levels are CMOS and TTL compatible with high input impedance.

FEATURES

- Wideband data output (600 kHz min.)
- Fast RSSI rise and fall times
- Low power consumption: 7.5 mA typ. at 5 V
- Mixer input to >500 MHz
- Mixer noise figure of 12 dB at 240 MHz
- XTAL oscillator effective to 150 MHz (L.C. oscillator to 1 GHz local oscillator can be injected)
- 92 dB of IF Amp/Limiter gain
- 25 MHz limiter small signal bandwidth
- Temperature compensated logarithmic Received Signal Strength Indicator (RSSI) with a dynamic range in excess of 90 dB
- RSSI output internal op amp
- Internal op amps with rail-to-rail outputs
- Low external component count; suitable for crystal/ceramic/LC filters
- Excellent sensitivity: 0.54 μV into 50 Ω matching network for 12 dB SINAD (Signal to Noise and Distortion ratio) for 1 kHz tone with RF at 240 MHz and IF at 10.7 MHz
- ESD hardened
- 10.7 MHz filter matching (330 Ω)
- Power-down mode (I_{CC} = 200 μA)

PIN CONFIGURATION

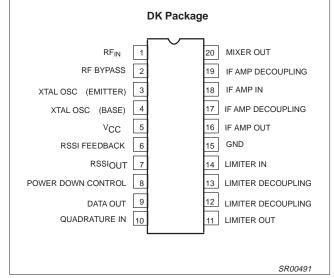


Figure 1. Pin configuration

APPLICATIONS

- DECT (Digital European Cordless Telephone)
- Digital cordless telephones
- Digital cellular telephones
- Portable high performance communications receivers
- Single conversion VHF/UHF receivers
- FSK and ASK data receivers
- Wireless LANs

ORDERING INFORMATION

DESCRIPTION	TEMPERATURE RANGE	ORDER CODE	DWG#
20-Pin Plastic Shrink Small Outline Package (Surface-mount)	–40 °C to +85 °C	SA58641DK	SOT266-1

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BLOCK DIAGRAM

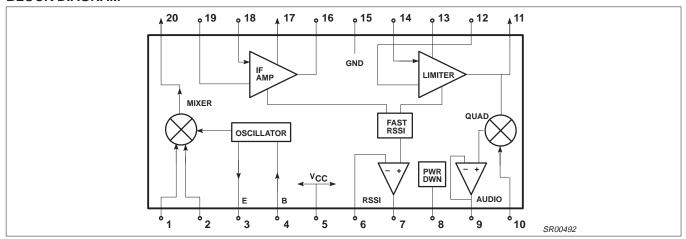


Figure 2. Block diagram

ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING	UNITS
V _{CC}	Single supply voltage	0.3 to 7	V
V _{IN}	Voltage applied to any other pin	-0.3 to (V _{CC} +0.3)	V
T _{stg}	Storage temperature range	-65 to +150	°C
T _{amb}	Operating ambient temperature range SA58641	-40 to +85	°C
θ_{JA}	Thermal impedance (DC package)	117	°C/W

DC ELECTRICAL CHARACTERISTICS

 V_{CC} = +5 V, T_{amb} = 25 °C; unless otherwise stated.

CVMDOL	DADAMETER	TEST CONDITIONS		LIMITS				
SYMBOL	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS		
V _{CC}	Power supply voltage range		4.5	5.0	5.5	V		
I _{CC}	DC current drain	Pin 8 = HIGH	5.5	7.5	8.5	mA		
	lanut aurrant	Pin 8 LOW	-10		10	μΑ		
	Input current	Pin 8 HIGH	-10		10	μΑ		
	lanut loval	Pin 8 LOW	0		0.3V _{CC}	V		
	Input level	Pin 8 HIGH	0.7V _{CC}		V _{CC}	V		
I _{CC}	Standby	Pin 8 = LOW		0.2	0.5	mA		
t _{ON}	Power-up time	RSSI valid (10% to 90%)		10		μs		
t _{OFF}	Power-down time	RSSI invalid (90% to 10%)		5		μs		

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AC ELECTRICAL CHARACTERISTICS

 T_{amb} = 25 °C; V_{CC} = +5 V, unless otherwise stated. RF frequency = 240.05 MHz + 14.5 dBV RF input step-up; IF frequency = 10.7 MHz; RF level = -45 dBm; FM modulation = 1 kHz with \pm 125 kHz peak deviation. Audio output with C-message weighted filter and de-emphasis capacitor. Test circuit Figure 1. The parameters listed below are tested using automatic test equipment to assure consistent electrical characteristics. The limits do not represent the ultimate performance limits of the device. Use of an optimized RF layout will improve many of the listed parameters.

SYMBOL	DADAMETED	TEST CONDITIONS		UNITS		
STWBUL	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	TUNITS
Mixer/Osc	section (ext LO = 160mV _{RMS})					
f _{IN}	Input signal frequency			500		MHz
fosc	External oscillator (buffer)			500		MHz
	Noise figure at 240 MHz			12		dB
	Third-order input intercept point	Matched f1=240.05 MHz; f2=240.35 MHz		-16		dBm
	Conversion power gain	Matched 14.5 dBV step-up	8	11		dB
	RF input resistance	Single-ended input		700		Ω
	RF input capacitance			3.5		pF
	Mixer output resistance	(Pin 20)		330		Ω
IF section	I	-				
	IF amp gain	330 Ω load		38		dB
	Limiter gain	330 Ω load		54		dB
	Input limiting –3dB	Test at Pin 18		-105		dBm
	AM rejection	80% AM 1 kHz		50		dB
	Data level	R _{LOAD} = 100 kΩ	120	130		${\rm mV}_{\rm RMS}$
	3 dB data bandwidth		600	700		kHz
	SINAD sensitivity	RF level = -111 dBm		16		dB
THD	Total harmonic distortion			-43	-38	dB
S/N	Signal-to-noise ratio	No modulation for noise		60		dB
		IF level = -90 dBm		0.6	1.0	V
	IF RSSI output with buffer	IF level = -45 dBm	0.2	1.2	1.8	V
		IF level = -10 dBm	0.8	1.6	2.3	V
	IF RSSI output rise time	IF frequency = 10.7 MHz				
	(10kHz pulse, no 10.7MHz filter)	RF level = -56 dBm		1.2		μs
	(no RSSI bypass capacitor)	RF level = -28 dBm		1.1		μs
	IF RSSI output fall time	IF frequency = 10.7 MHz			•	
	(10 kHz pulse, no 10.7 MHz filter)	RF level = -56 dBm		2.0		μs
	(no RSSI bypass capacitor)	RF level = -28 dBm		7.3		μs
	RSSI range			70		dB
	RSSI accuracy			±2.0		dB
	IF input impedance			330		Ω
	IF output impedance			330		Ω
	Limiter input impedance			330		Ω
	Limiter output impedance			300		Ω
	Limiter output level with no load			130		mV_{RMS}
RF/IF sec	tion (int LO)				•	-
	System RSSI output	RF level = -10 dBm		1.4		V
	System SINAD	RF level = -95 dBm		12	İ	dB

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PERFORMANCE CHARACTERISTICS

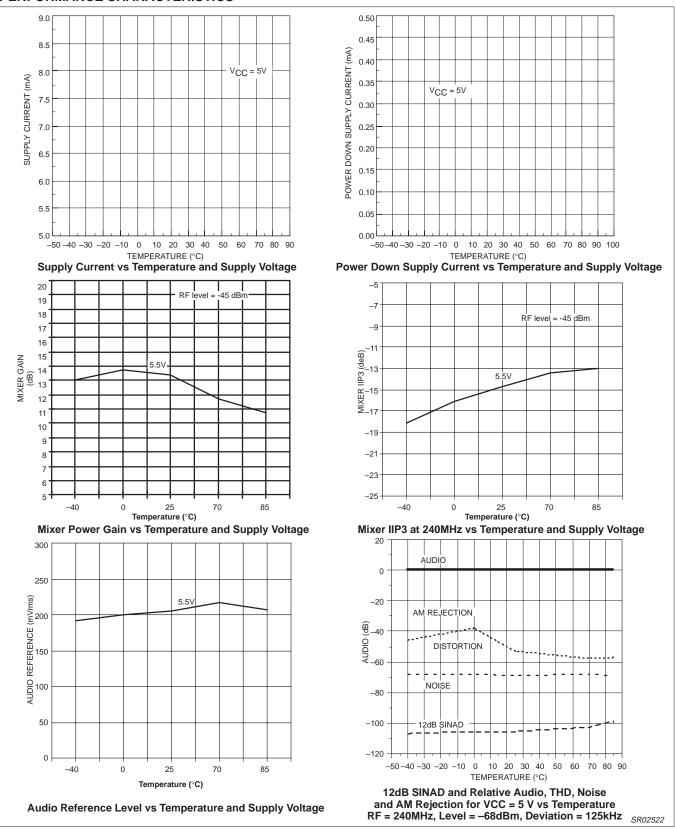


Figure 3. Performance Characteristics

PERFORMANCE CHARACTERISTICS (continued)

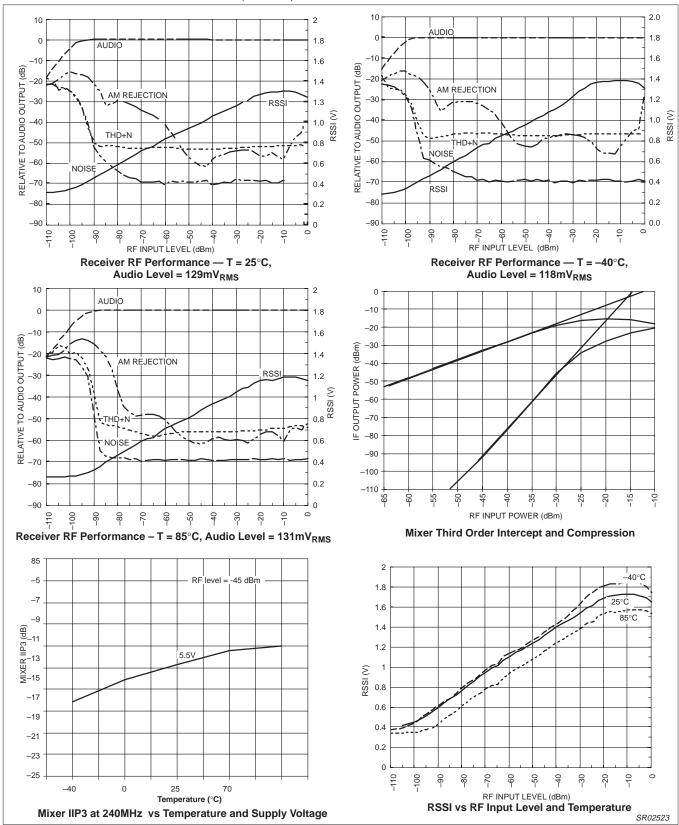


Figure 4. Performance Characteristics

PERFORMANCE CHARACTERISTICS (continued)

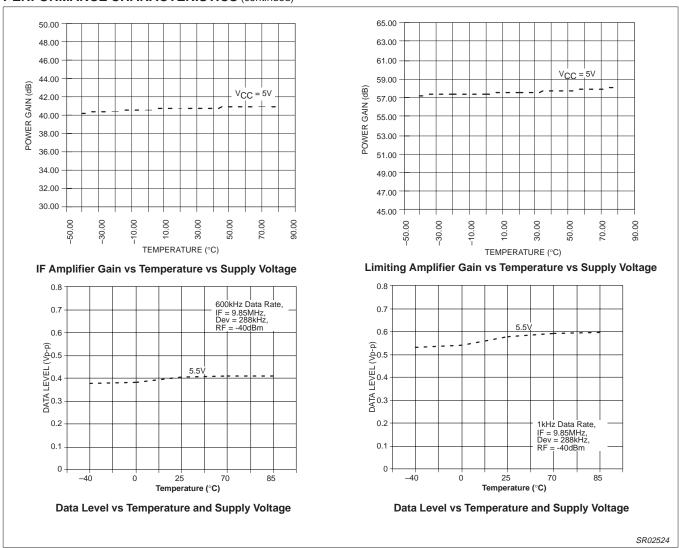


Figure 5. Performance Characteristics

PERFORMANCE CHARACTERISTICS (continued)

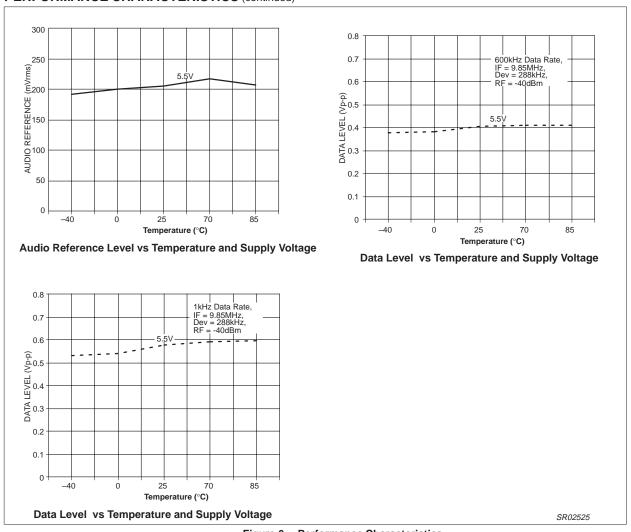


Figure 6. Performance Characteristics

PIN FUNCTIONS

PIN No.	PIN MNEMONIC	DC V	EQUIVALENT CIRCUIT	PIN No.	PIN MNEMONIC	DC V	EQUIVALENT CIRCUIT
1	RFIN	+1.07	→ 0.8k → 0.8k	6	RSSI FEEDBACK	+0.20	VCC +
2	RF BYPASS	+1.07		7	RSSI OUT	+0.20	v _{cc}
3	XTAL OSC	+1.57	∆ § 18k 4 MIX	8	POWER DOWN	+2.75	R R
4	XTAL OSC	+2.32	3 = 150μA	9	DATA OUT	+1.09	vcc = =
5	V _{CC}	+3.00	VREF O O O O O O O O O O O O O O O O O O O	10	QUAD. IN	+3.00	20μA SR00497

Figure 7. Pin Functions

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PIN FUNCTIONS (continued)

PIN No.	PIN MNEMONIC	DC V	EQUIVALENT CIRCUIT	PIN No.	PIN MNEMONIC	DC V	EQUIVALENT CIRCUIT
11	LIMITER OUT	+1.35	8.8k \(\frac{11}{2} \)	16	IF AMP OUT	+1.22	140Ω 18.8k
12	LIMITER DECOUP	+1.23		17	IF AMP DECOUP	+1.22	
13	LIMITER COUPLING	+1.23	330Ω 50μA =	18	IF AMP IN	+1.22	18 330Ω 50μA 17
14	LIMITER IN	+1.23		19	IF AMP DECOUP	+1.22	
15	GND	0		20	MIXER OUT	+1.03	110Ω Z 110Ω Z 400μA = SR00498

Figure 8. Pin Functions (cont.)

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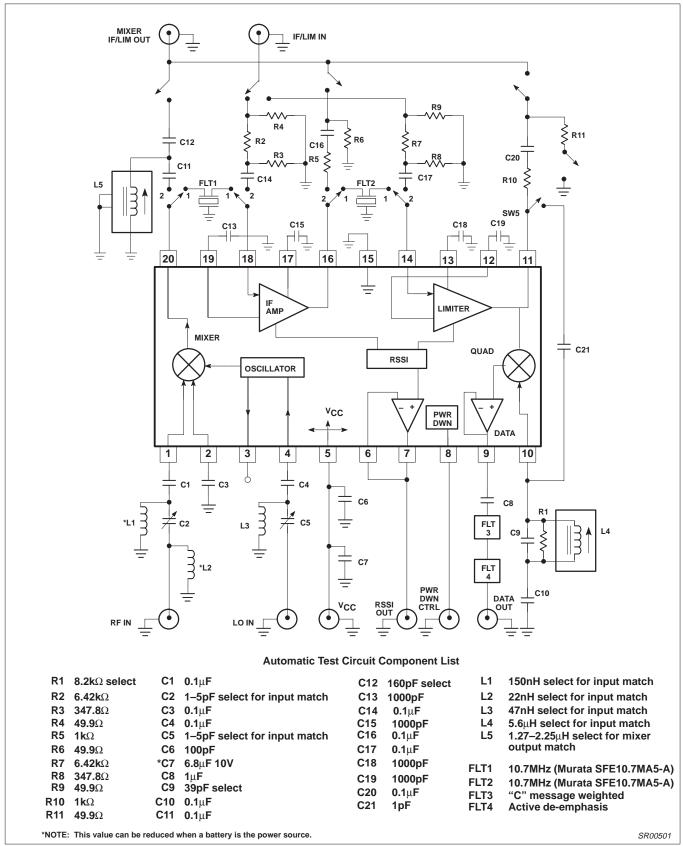


Figure 9. SA58641 240.05MHz (RF) / 10.7MHz (IF) Test Circuit

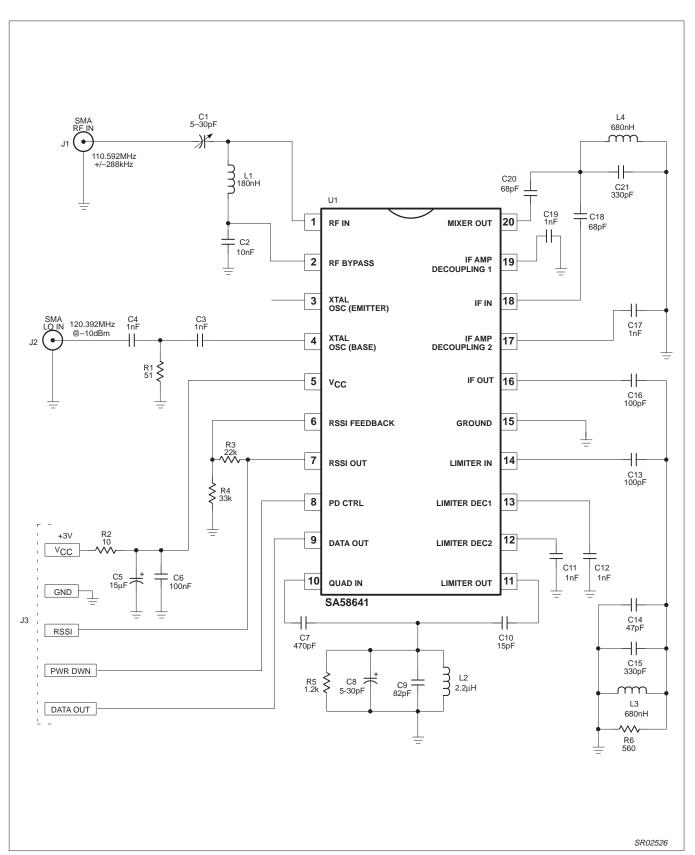


Figure 10. SA58641 110.592 MHz (RF) / 9.8 MHz (IF) DECT Application Circuit

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Table 1. DECT Application Circuit Electrical Characteristics

RF frequency = 110.592 MHz; IF frequency = 9.8 MHz; RF level = -45 dBm; FM modulation = 100 kHz with ±288 kHz peak deviation.

SYMBOL	PARAMETER	TEST CONDITIONS	TYPICAL	UNITS	
Mixer/Osc s	section (ext LO = 160 mV _{RMS})				
PG	Conversion power gain		13	dB	
NF	Noise Figure at 110 MHz		12	dB	
IIP3	Third order input intercept	Matched f1 = 110.592 MHz; f2 = 110.892 MHz	-15	dBm	
R _{IN}	RF input resistance		690	Ω	
C _{IN}	RF input capacitance		3.6	pF	
IF section					
	IF amp gain	330 Ω load	38	dB	
	Limiter amp gain	330 Ω load	54	dB	
	Data level	$R_{LOAD} = 3 \text{ k}\Omega$	130	mV _{RMS}	
	3 dB data bandwidth		700	kHz	
RF/IF section	on (internal LO)				
	System RSSI output	RF level = -10 dBm	1.4	V	
	System S/N ¹	RF level = -83 dBm	10	dB	

NOTE:

1. 10 dB S/N corresponds to BER = 10^{-3} .

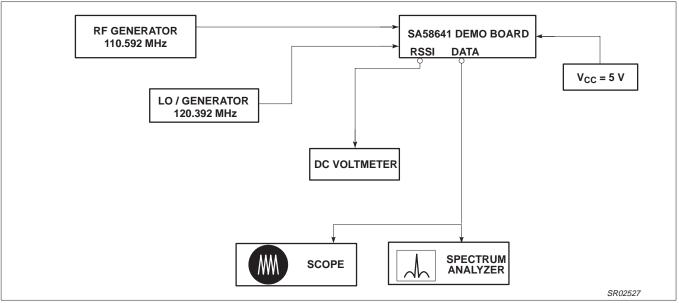


Figure 11. SA58641 Application Circuit Test Set Up

NOTES:

- 1. RF generator: Set your RF generator at 110.592 MHz, use a 100 kHz modulation frequency and a ± 288 kHz deviation.
- 2. Layout: The layout is very critical in the performance of the receiver. We highly recommend our demo board layout.
- 3. RSSI: The smallest RSSI voltage (i.e., when no RF input is present and the input is terminated) is a measure of the quality of the layout and design. If the lowest RSSI voltage is 500 mV or higher, it means the receiver is in regenerative mode. In that case, the receiver sensitivity will be worse than expected.
- 4. Supply bypass and shielding: All of the inductors, the quad tank, and their shield must be grounded. A 0.1 μF bypass capacitor on the supply pin improves sensitivity.

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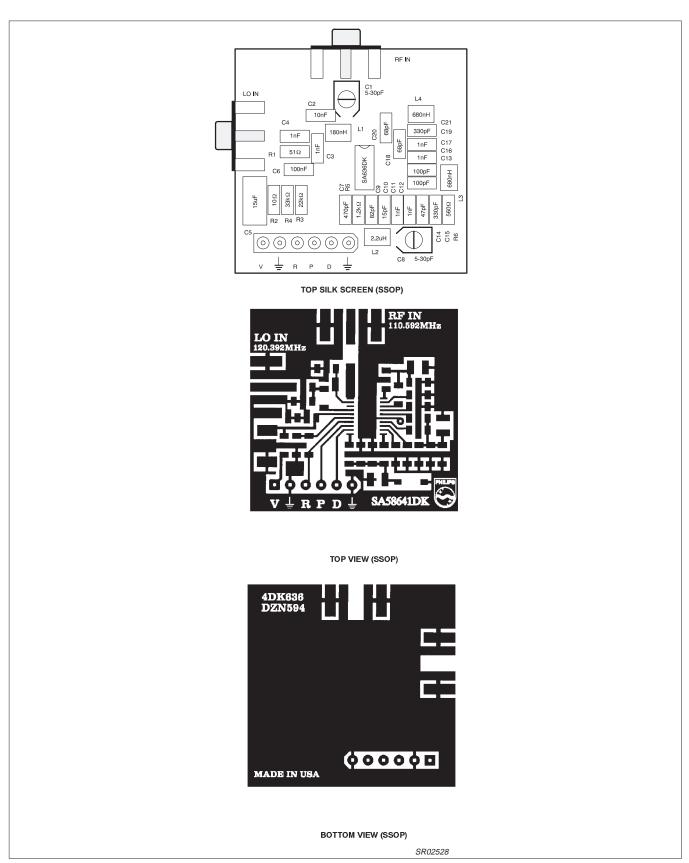


Figure 12. SA58641 Demoboard Layout (Not Actual Size)

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CIRCUIT DESCRIPTION

The SA58641 is an IF signal processing system suitable for second IF or single conversion systems with input frequency as high as 1 GHz. The bandwidth of the IF amplifier is about 40 MHz, with 38 dB of gain from a 50 Ω source. The bandwidth of the limiter is about 28 MHz with about 54 dB of gain from a 50 Ω source. However, the gain/bandwidth distribution is optimized for 10.7 MHz, 330 Ω source applications. The overall system is well-suited to battery operation as well as high performance and high quality products of all types, such as cordless and cellular hand-held phones.

The input stage is a Gilbert cell mixer with oscillator. Typical mixer characteristics include a noise figure of 14 dB, conversion gain of 11 dB, and input third-order intercept of –16 dBm. The oscillator will operate in excess of 1 GHz in L/C tank configurations. Hartley or Colpitts circuits can be used up to 100 MHz for xtal configurations. Butler oscillators are recommended for xtal configurations up to 150 MHz.

The output of the mixer is internally loaded with a 330 Ω resistor permitting direct connection to a 10.7 MHz ceramic filter for narrowband applications. The input resistance of the limiting IF amplifiers is also 330 Ω . With most 10.7 MHz ceramic filters and many crystal filters, no impedance matching network is necessary. For applications requiring wideband IF filtering, such as DECT, external LC filters are used (see Figure 10). To achieve optimum linearity of the log signal strength indicator, there must be a 6 dB(v)

insertion loss between the first and second IF stages. If the IF filter or interstage network does not cause 6 dB(v) insertion loss, a fixed or variable resistor can be added between the first IF output (Pin 16) and the interstage network.

The signal from the second limiting amplifier goes to a Gilbert cell quadrature detector. One port of the Gilbert cell is internally driven by the IF. The other output of the IF is AC-coupled to a tuned quadrature network. This signal, which now has a 90° phase relationship to the internal signal, drives the other port of the multiplier cell.

Overall, the IF section has a gain of 90 dB. For operation at intermediate frequency at 10.7 MHz. Special care must be given to layout, termination, and interstage loss to avoid instability.

The demodulated output (DATA) of the quadrature is a voltage output. This output is designed to handle a minimum bandwidth of 600 kHz. This is designed to demodulate wideband data, such as in DECT applications.

A Receive Signal Strength Indicator (RSSI) completes the circuitry. The output range is greater than 90 dB and is temperature compensated. This log signal strength indicator exceeds the criteria for AMPS or TACS cellular telephone, DECT and RCR-28 cordless telephone. This signal drives an internal op amp. The op amp is capable of rail-to-rail output. It can be used for gain, filtering, or 2nd-order temperature compensation of the RSSI, if needed.

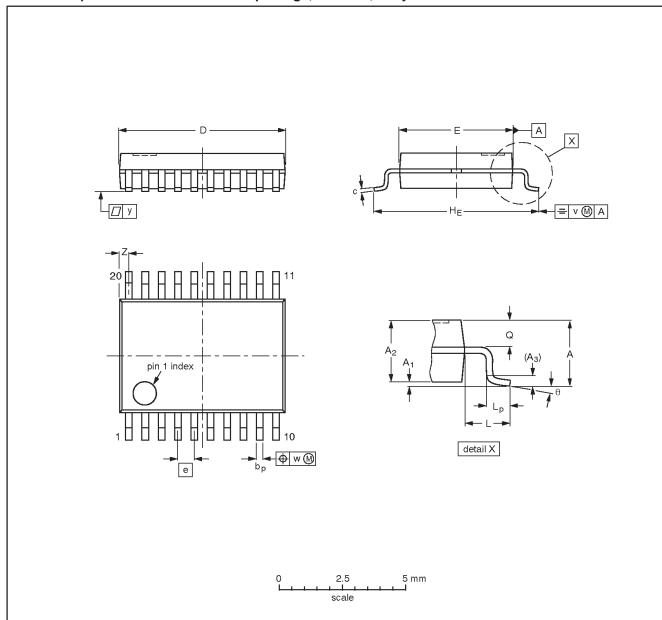
NOTE: $dB(v) = 20log V_{OUT}/V_{IN}$

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SSOP20: plastic shrink small outline package; 20 leads; body width 4.4 mm

SOT266-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₁	A ₂	А3	bp	C	D ⁽¹⁾	E ⁽¹⁾	e	HE	L	Lp	ø	>	w	у	z ⁽¹⁾	θ
mm	1.5	0.15 0	1.4 1.2	0.25	0.32 0.20	0.20 0.13	6.6 6.4	4.5 4.3	0.65	6.6 6.2	1	0.75 0.45	0.65 0.45	0.2	0.13	0.1	0.48 0.18	10° 0°

Note

1. Plastic or metal protrusions of 0.20 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT266-1		MO-152				-99-12-27 03-02-19

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REVISION HISTORY

Rev	Date	Description
_1	20041216	Product data (9397 750 14339).

Data sheet status

Level	Data sheet status [1]	Product status ^{[2] [3]}	Definitions
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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